High Power SOA Chip on Carrier



Part Number: COC-290

High Power SOA Chip on Carrier Single-Mode SOA Tilted Straight Waveguide Wavelength at 1310nm

Features

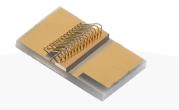
- High Output Power
- Broad Gain Bandwidth
- High Dynamic Range
- High Efficiency
- Standard SOA Chip on Carrier
- Cost Effective

Application

- Optical Communications
- LiDAR
- Free Space Communications
- Network Test Equipment



SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary, we will further optimize the design of our InP & GaSb laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.



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Specification

COC-290



Optical	Symbol	Тур.	Units
Center Wavelength	λ _c	1310	nm
Output Power @1A*	Pout	0.45	Watts (±10%)
Aperture Width	AW	4	μm
Aperture Height	AH	1	μm
Gain @ Pin = 10µW	G	35	dB
Beam Exit Angle	θεχτ	19.5	Degree
Beam Exit Angle	θεχτ	19.5	Degree
Noise Figure	NF	6	dB
Polarization Extinction Ratio	PER	18	dB
Fast Axis Div.	ΘT	30	Deg FWHM
Slow Axis Div.	Θ∥	16	Deg FWHM
Front Facet Reflectivity		<0.1%	
Rear Face Reflectivity		<0.1%	
Waveguide		Tilted Straight	
Electrical	Symbol		Units
Operating Current	l _{op}	1	A
Operating Voltage	V _{op}	2	V
Mechanical		Range	Units
Chip Width		500	μm
Operating Temp.**		-40 to 100	°C
Storage Temp.		-40 to 100	°C

*Optical Power for 1310nm COC-288 and COC-290 with SOA drive current @ 1A and estimated Pin @ 7mW *Optical Power for 1550nm COC-285 and COC-287 with SOA drive current @ 1A and estimated Pin @ 21mW * Optical output power depends on the seed laser power, coupling efficiency, and thermal management.

> *Specified values are rated at a constant heat sink temperature of 20°C. **High temperature operation will reduce performance and MTTF.

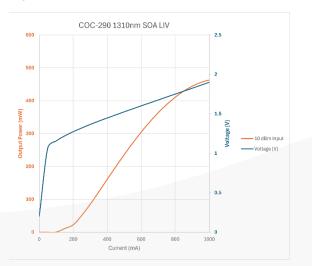
Unless otherwise indicated all values are nominal.

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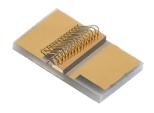
SemiNex SOA COC-290

Graphs & Data Typical COC L-I-V Characteristics



Typical COC Output Spectrum

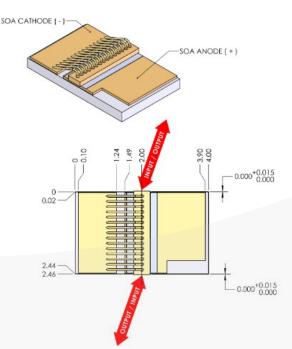
COC-290 1310 SOA Spectrum at 500mA 1.0 0.8 Normalized Intensity (a.u.) 0.6 0.4 0.2 0.0 1100 1150 1200 1250 1300 1350 1400 1450 1500 Wavelength (nm) SemiNex Corporation • 153 Andover Street, Suite 201, Danvers, MA 01923 • 978-326-7700 • sales@seminex.com



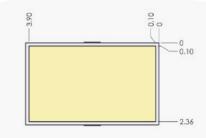
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Mechanical Drawing







*Graphs and Data were collected from mounted parts

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